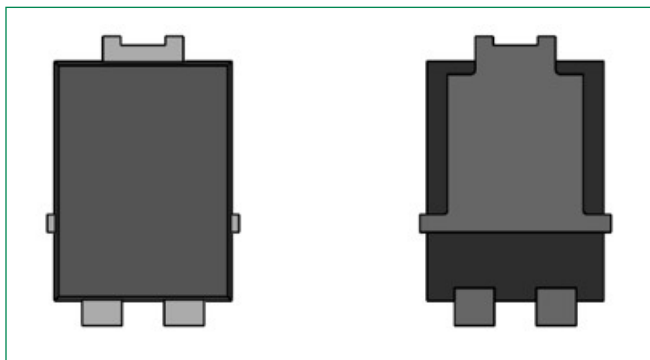
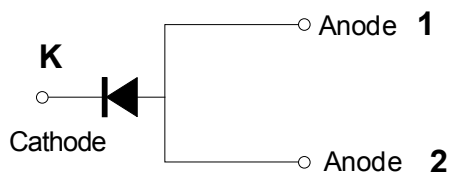


DST10100S-A



Pin out



Description

Littelfuse DST series Ultra Low V_F Schottky Barrier Rectifier is designed to meet the general requirements of commercial and industrial applications by providing high temperature, low leakage and lower V_F products.

It is suitable for high frequency switching mode power supply, free-wheeling diodes and polarity protection diodes.

Features

- High reliability application and AEC-Q101 qualified.
- Ultra low forward voltage drop
- High frequency operation
- MSL: Level 1 - unlimited
- High junction temperature capability
- Trench MOS Schottky technology
- Single die in TO-277B Package
- Pb-free E3 means 2nd level interconnect is Pb-free and the terminal finish material is tin(Sn) (IPC/ JEDEC J-STD-609A.01)

Applications

- Switching mode power supply
- DC/DC converters
- Free-Wheeling diodes
- Polarity Protection Diodes

Maximum Ratings

Parameters	Symbol	Test Conditions	Max	Unit
Peak Inverse Voltage	V_{RWM}	-	100	V
Single Peak Reverse Voltage	V_{RSM}	-	105	V
Average Forward Current*	$I_{F(AV)}$	50% duty cycle @ $T_L = 125^\circ\text{C}$ rectangular wave form	10	A
Peak One Cycle Non-Repetitive Surge	I_{FSM}	8.3 ms, half Sine pulse	150	A

* Mounted on 30 mm x 30 mm pad areas aluminum PCB

Electrical Characteristics

Parameters	Symbol	Test Conditions	Max	Unit
Forward Voltage Drop *	V_{F1}	@2A, Pulse, $T_J = -40^\circ\text{C}$	0.60	V
	V_{F2}	@5A, Pulse, $T_J = -40^\circ\text{C}$	0.65	
	V_{F3}	@10A, Pulse, $T_J = -40^\circ\text{C}$	0.70	
	V_{F4}	@2A, Pulse, $T_J = 25^\circ\text{C}$	0.50	
	V_{F5}	@5A, Pulse, $T_J = 25^\circ\text{C}$	0.60	
	V_{F6}	@10A, Pulse, $T_J = 25^\circ\text{C}$	0.70	
	V_{F7}	@2A, Pulse, $T_J = 125^\circ\text{C}$	0.40	
	V_{F8}	@5A, Pulse, $T_J = 125^\circ\text{C}$	0.55	
	V_{F9}	@10A, Pulse, $T_J = 125^\circ\text{C}$	0.65	
Reverse Current *	I_{R1}	@ V_R = rated V_R , $T_J = 25^\circ\text{C}$	0.25	mA
	I_{R2}	@ V_R = rated V_R , $T_J = 125^\circ\text{C}$	36	

* Pulse Width < 300 μ s, Duty Cycle < 2%

Thermal-Mechanical Specifications

Parameters	Symbol	Test Conditions	Max	Unit
Junction Temperature	T_J		-55 to +150	°C
Storage Temperature	T_{stg}		-55 to +150	°C
Maximum Thermal Resistance Junction to Ambient	R_{thJA}	DC operation	75	°C/W
Maximum Thermal Resistance Junction to Lead	R_{thJL}^*		3.5	°C/W
Approximate Weight	wt		0.08	g
Case Style	TO-277B			

*Lead temperature monitored at the cathode pin

Figure 1: Forward Current Derating Curve

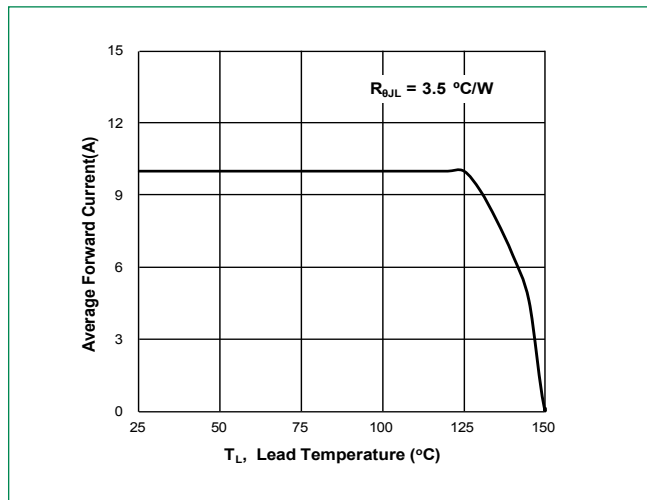


Figure 2: Forward Power Loss Characteristics

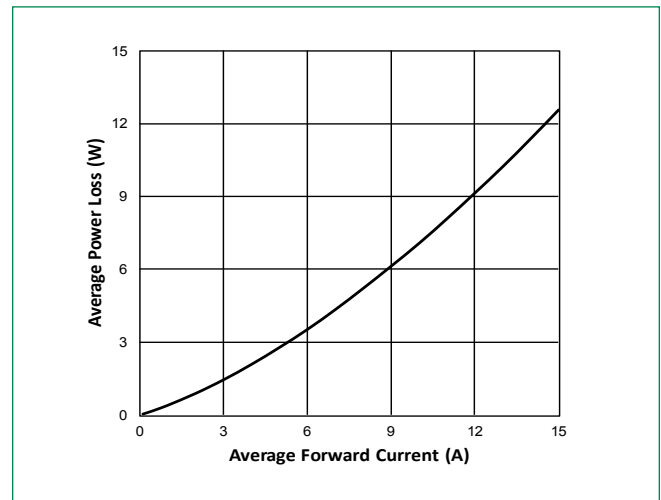


Figure 3: Typical Forward Characteristics

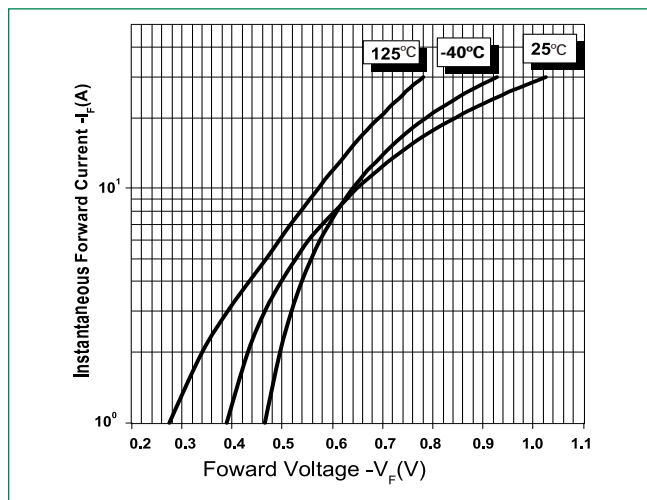


Figure 4: Typical Reverse Characteristics

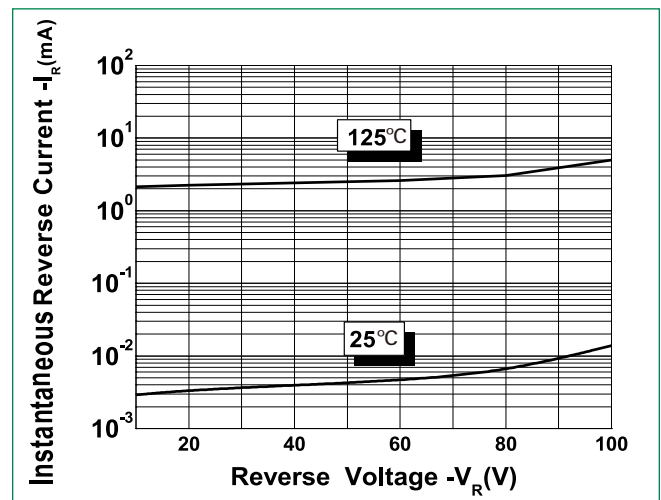
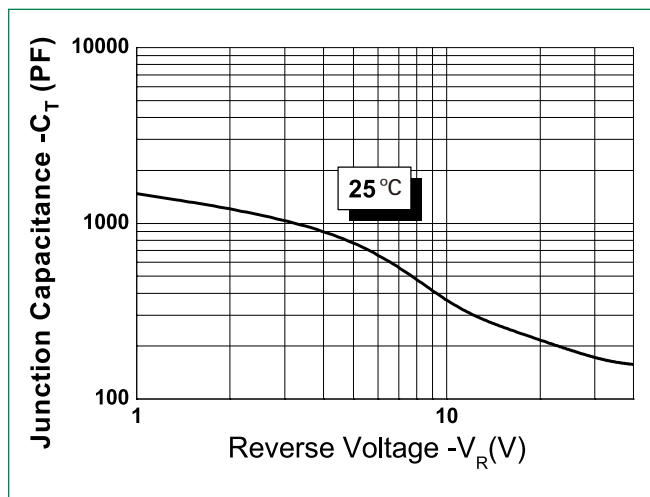
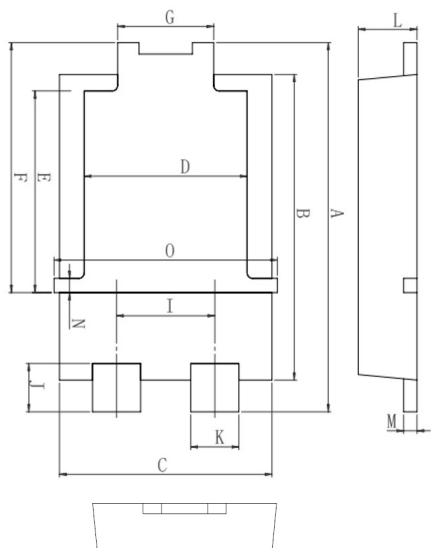


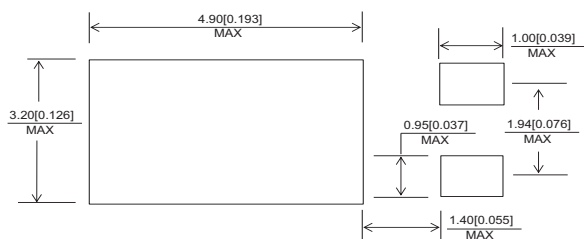
Figure 5: Typical Junction Capacitance



Dimensions-TO-277B

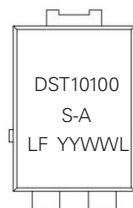


Mounting Pad Layout



Symbol	Millimeters		
	Min	Typ	Max
A	6.30	6.50	6.70
B	5.28	5.38	5.48
C	3.88	3.98	4.08
D	2.90	3.05	3.20
E	3.40	3.55	3.70
F	4.20	4.40	4.60
G	1.70	1.80	1.90
I	1.74	1.84	1.94
J	0.65	0.85	1.05
K	0.85	0.90	0.95
L	0.95	1.10	1.25
M	0.20	0.25	0.30
N	0.25	0.40	0.55
O	4.00	4.05	4.25

Part Numbering and Marking System

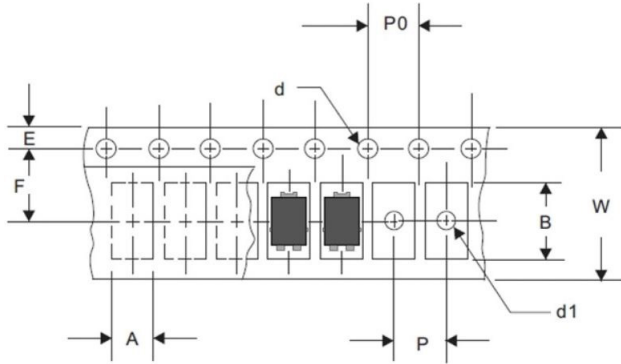


DST = Device Type
 10 = Forward Current (10A)
 100 = Reverse Voltage (100V)
 S = Package Type
 A = AEC-Q101 qualified device
 LF = Littelfuse
 YY = Year
 WW = Week
 L = Lot Number

Packing Options

Part Number	Marking	Packing Mode	M.O.Q
DST10100S-A	DST10100S-A	5000pcs / Reel	5000

Carrier Tape & Reel Specification



Symbol	Millimeters	
	Min	Max
A	4.28	4.48
B	6.80	7.00
d	1.40	1.60
d1	-	1.50
E	1.65	1.85
F	7.40	7.60
P	5.40	5.60
P0	3.90	4.10
W	11.70	12.30

Disclaimer Notice

Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <http://www.littelfuse.com/disclaimer-electronics>.



Part of:

